NSN 5962-01-298-6816

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Body Length:	
0.840 inches	
Body Width:	
	nches and 0.310 inches
Body Height:	
	nches and 0.185 inches
	r Dissipation Rating:
500.0 milliwatts	
	purature Range:
55.0/+125.0 deg	
Storage Tempu	
-65.0/+150.0 deg	
Features Provid	
	led and burn in and programmable and positive outputs
nclosure Mater	ial:
Ceramic	
nclosure Config	juration:
Dual-in-line	
Output Logic Fo	
Transistor-transis	-
nput Circuit Pa	ttern:
10 input	
ase Outline Sc	purce And Designator:
D-2 mil-m-38510	
Ferminal Surfac	e Treatment:
Solder	
Voltage Rating	And Type Per Characteristic:
0.5 volts power	source and 7.0 volts power source
Time Rating Per	Chacteristic:
60.00 nanosecor	nds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level
output	
Memory Device	Туре:
Rom	
Memory Capaci	ty:
Unknown	
Test Data Docu	ment:
96906-mil-std-88	3 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type A	And Quantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure	

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

